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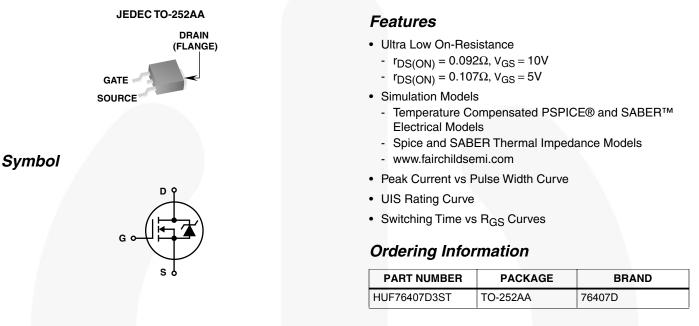
### HUF76407D3S

Data Sheet

October 2013

# N-Channel Logic Level UltraFET Power MOSFET 60 V, 11 A, 107 m $\Omega$

### Packaging



#### Absolute Maximum Ratings $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	HUF76407D3ST	UNITS
Drain to Source Voltage (Note 1)	60	V
Drain to Gate Voltage ( $R_{GS} = 20k\Omega$ ) (Note 1)	60	V
Gate to Source Voltage	±16	V
Drain Current		
Continuous (T <sub>C</sub> = $25^{\circ}$ C, V <sub>GS</sub> = 5V)	11	А
Continuous (T <sub>C</sub> = $25^{\circ}$ C, V <sub>GS</sub> = 10V) (Figure 2)I <sub>D</sub>	12	А
Continuous ( $T_C = 135^{\circ}C$ , $V_{GS} = 5V$ ) $I_D$	6	А
Continuous (T <sub>C</sub> = 135 <sup>o</sup> C, V <sub>GS</sub> = 4.5V) (Figure 2)	6	А
Pulsed Drain CurrentI <sub>DM</sub>	Figure 4	
Pulsed Avalanche RatingUIS	Figures 6, 14, 15	
Power Dissipation	38	W
Derate Above 25°C	0.25	W/ <sup>o</sup> C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering		
Leads at 0.063in (1.6mm) from Case for 10sT	300	°C
Package Body for 10s, See Techbrief TB334	260	°C
NOTE:		

1.  $T_J = 25^{\circ}C$  to  $150^{\circ}C$ .

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### For severe environments, see our Automotive HUFA series.

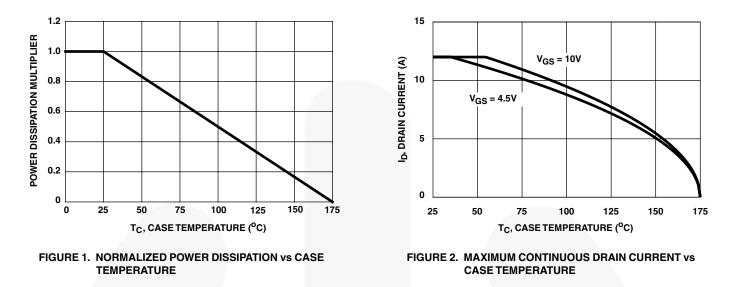
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN	ТҮР	MAX	UNITS
OFF STATE SPECIFICATIONS				1			
Drain to Source Breakdown Voltage	BV <sub>DSS</sub>	$I_{D} = 250 \mu A, V_{GS} = 0$	V (Figure 12)	60	-	-	V
		$I_{\rm D} = 250 \mu {\rm A}, V_{\rm GS} = 0$	V , T <sub>C</sub> = -40 <sup>0</sup> C (Figure 12)	55	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			-	-	1	μA
		$V_{DS} = 50V, V_{GS} = 0$	V, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	250	μA
Gate to Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±16V		-	-	±100	nA
ON STATE SPECIFICATIONS							
Gate to Source Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_{D} = 250$	μA (Figure 11)	1	-	3	V
Drain to Source On Resistance	r <sub>DS(ON)</sub>			-	0.077	0.092	Ω
		$I_{\rm D} = 8A, V_{\rm GS} = 5V$ (F		-	0.095	0.107	Ω
		$I_{\rm D} = 8A, V_{\rm GS} = 4.5V$ (Figure 9)		-	0.107	0.117	Ω
THERMAL SPECIFICATIONS							
Thermal Resistance Junction to Case	R <sub>0JC</sub>	TO-252		-	-	3.94	°C/W
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	_		-	-	100	°C/W
SWITCHING SPECIFICATIONS (VGS	= 4.5V)						1
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> = 30V, I <sub>D</sub> = 8A		-	-	170	ns
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{GS} = 4.5V, R_{GS} = 3$	32Ω	-	8	-	ns
Rise Time	t <sub>r</sub>	_ (Figures 15, 21, 22)			105	-	ns
Turn-Off Delay Time	t <sub>d(OFF)</sub>	-		-	22	-	ns
Fall Time	t <sub>f</sub>	-		-	39	-	ns
Turn-Off Time	tOFF			-	-	92	ns
SWITCHING SPECIFICATIONS (VGS							1
Turn-On Time	ton	V <sub>DD</sub> = 30V, I <sub>D</sub> = 13A		-	-	56	ns
Turn-On Delay Time	t <sub>d(ON)</sub>	V <sub>GS</sub> = 10V,		-	5	-	ns
Rise Time	t <sub>r</sub>	$R_{GS} = 32\Omega$ (Figures 16, 21, 22)		-	32	-	ns
Turn-Off Delay Time	t <sub>d(OFF)</sub>			-	43	-	ns
Fall Time	t <sub>f</sub>	-		-	45	-	ns
Turn-Off Time	tOFF	_		-	-	132	ns
GATE CHARGE SPECIFICATIONS	-						
Total Gate Charge	Q <sub>g(TOT)</sub>	$V_{GS} = 0V$ to 10V	V <sub>DD</sub> = 30V,	-	9.4	11.3	nC
Gate Charge at 5V	Q <sub>g(5)</sub>	$V_{GS} = 0V \text{ to } 5V$	<sup>−−</sup> I <sub>D</sub> = 8A,	-	5.2	6.2	nC
Threshold Gate Charge	Q <sub>g(TH)</sub>	$V_{GS} = 0V \text{ to } 1V$	$I_{g(REF)} = 1.0 \text{mA}$	-	0.36	0.43	nC
Gate to Source Gate Charge	Q <sub>gs</sub>	(Figures 14, 19, 20)	-	1.2	-	nC	
Reverse Transfer Capacitance	Q <sub>gd</sub>			-	2.5	-	nC
CAPACITANCE SPECIFICATIONS	94						I
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0	V,	-	350	-	pF
Output Capacitance	C <sub>OSS</sub>	f = 1MHz (Figure 13)		-	105	-	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			-	23		pF

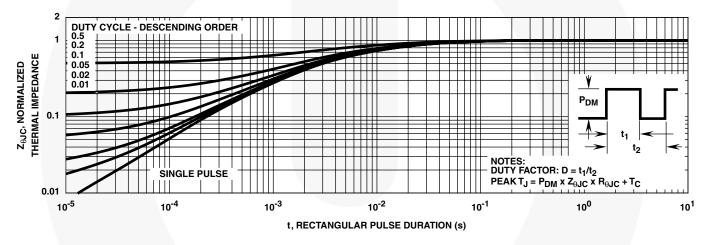
#### **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

#### Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	МАХ	UNITS
Source to Drain Diode Voltage	V <sub>SD</sub>	I <sub>SD</sub> =8A	-	-	1.25	V
		I <sub>SD</sub> = 3A	-	-	1.0	V
Reverse Recovery Time	t <sub>rr</sub>	$I_{SD} = 8A$ , $dI_{SD}/dt = 100A/\mu s$		-	66	ns
Reverse Recovered Charge	Q <sub>RR</sub>	$I_{SD} = 8A$ , $dI_{SD}/dt = 100A/\mu s$		-	159	nC

#### **Typical Performance Curves**







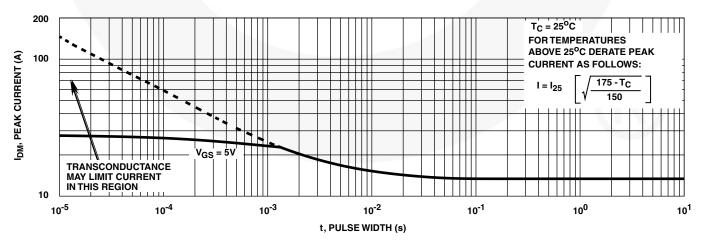


FIGURE 4. PEAK CURRENT CAPABILITY



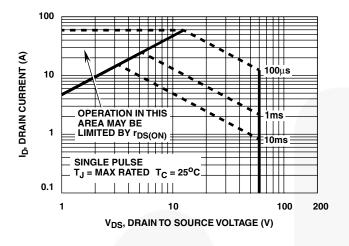


FIGURE 5. FORWARD BIAS SAFE OPERATING AREA

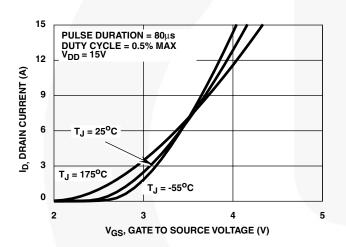
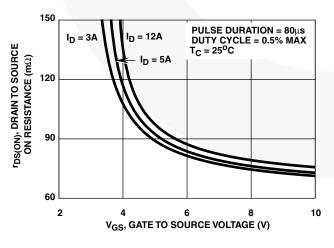
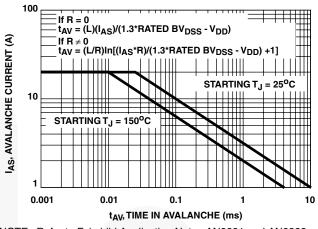


FIGURE 7. TRANSFER CHARACTERISTICS

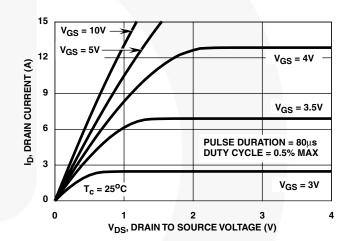






NOTE: Refer to Fairchild Application Notes AN9321 and AN9322. FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING

CAPABILITY





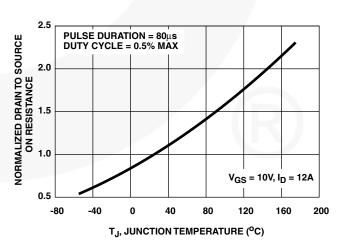
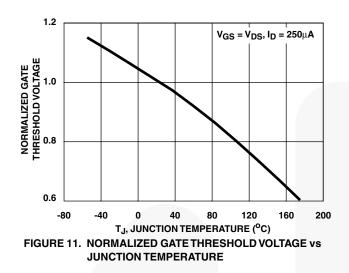


FIGURE 10. NORMALIZED DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

#### Typical Performance Curves (Continued)



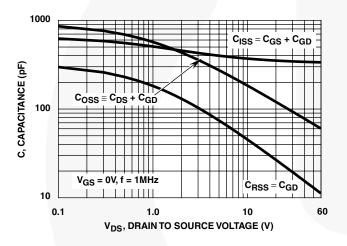


FIGURE 13. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

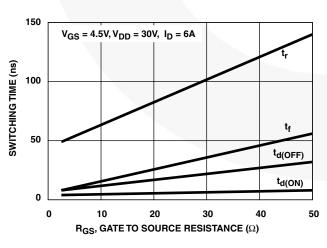


FIGURE 15. SWITCHING TIME vs GATE RESISTANCE

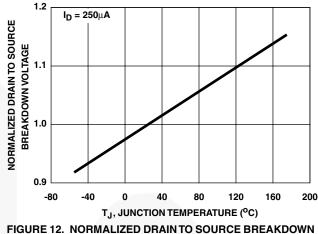
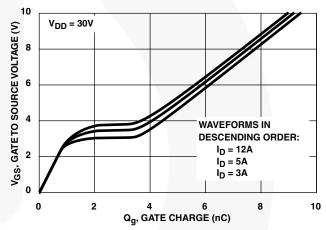


FIGURE 12. NORMALIZED DRAIN TO SOURCE BREAKDOWN VOLTAGE vs JUNCTION TEMPERATURE



NOTE: Refer to Fairchild Application Notes AN7254 and AN7260. FIGURE 14. GATE CHARGE WAVEFORMS FOR CONSTANT GATE CURRENT

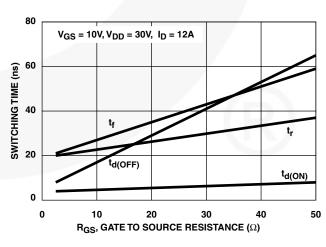


FIGURE 16. SWITCHING TIME vs GATE RESISTANCE

#### Test Circuits and Waveforms

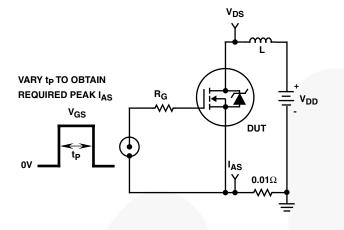


FIGURE 17. UNCLAMPED ENERGY TEST CIRCUIT

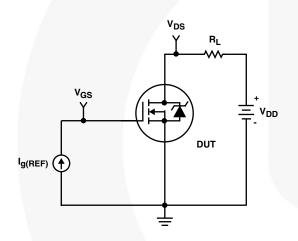


FIGURE 19. GATE CHARGE TEST CIRCUIT

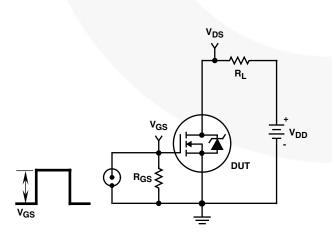


FIGURE 21. SWITCHING TIME TEST CIRCUIT

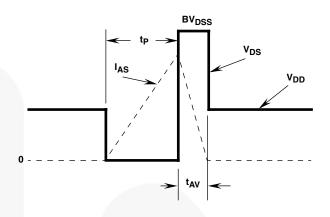


FIGURE 18. UNCLAMPED ENERGY WAVEFORMS

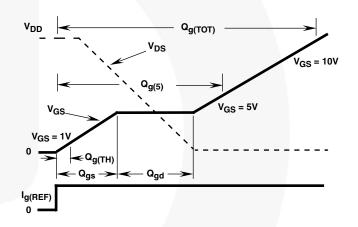


FIGURE 20. GATE CHARGE WAVEFORMS

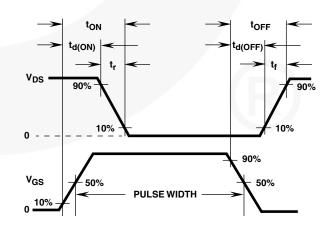
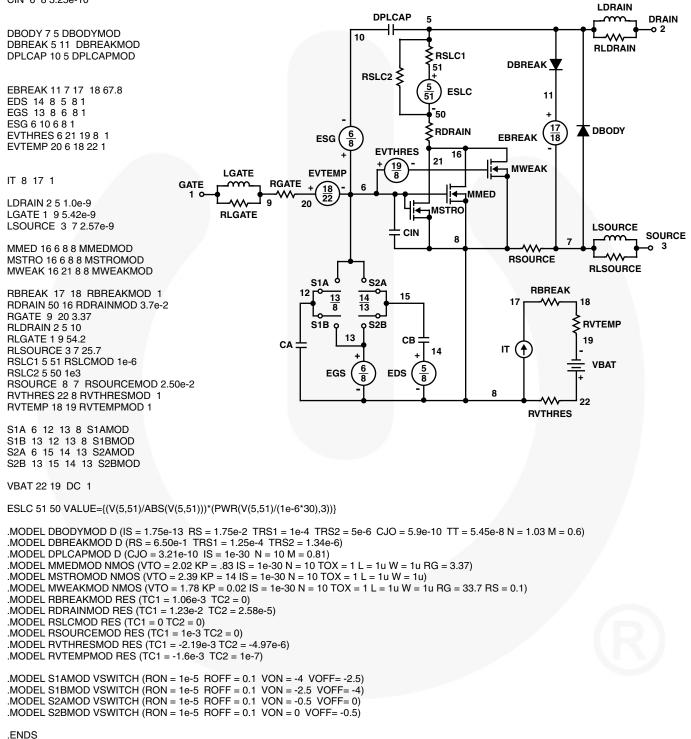


FIGURE 22. SWITCHING TIME WAVEFORM

#### **PSPICE Electrical Model**

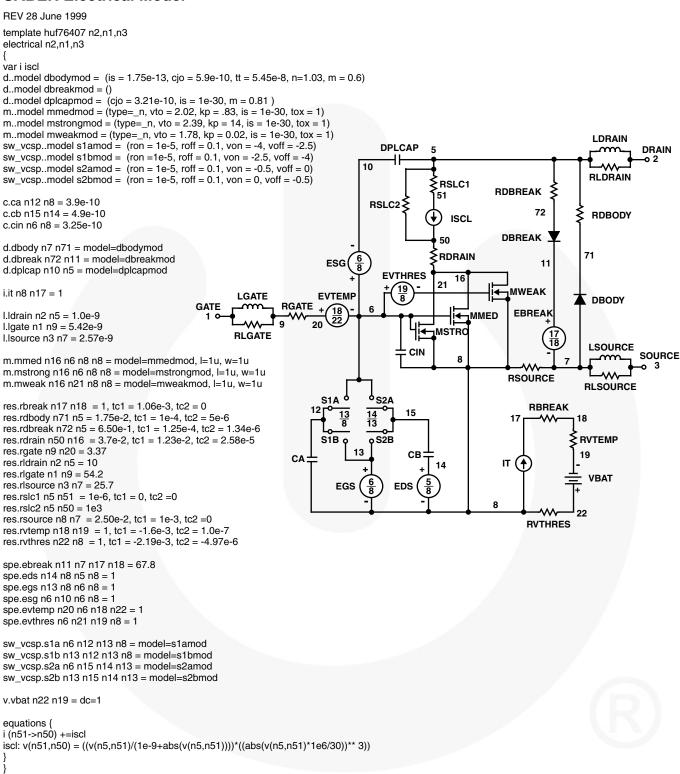
.SUBCKT HUF76407 2 1 3 ; rev 28June 1999

CA 12 8 3.9e-9 CB 15 14 4.9e-9 CIN 6 8 3.25e-10



NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.

#### SABER Electrical Model



#### SPICE Thermal Model

REV 28June 1999

HUF76407T

CTHERM1 th 6 4.5e-4 CTHERM2 6 5 2.5e-3 CTHERM3 5 4 1.9e-3 CTHERM4 4 3 2.6e-3 CTHERM5 3 2 5.5e-3 CTHERM6 2 tl 1.8e-2

RTHERM1 th 6 3.1e-2 RTHERM2 6 5 15.1e-2 RTHERM3 5 4 4.2e-1 RTHERM4 4 3 8.4e-1 RTHERM5 3 2 8.7e-1 RTHERM6 2 tl 1.5

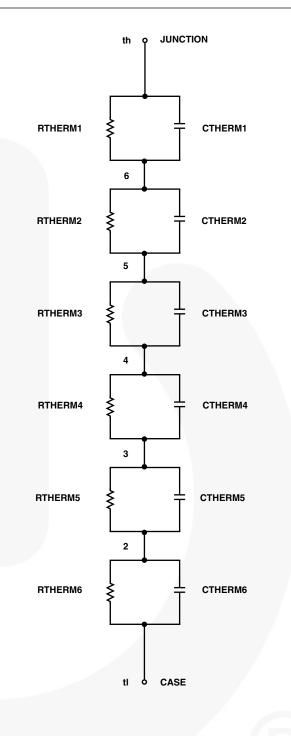
#### SABER Thermal Model

SABER thermal model HUF76407T

template thermal\_model th tl thermal\_c th, tl

ctherm.ctherm1 th 6 = 4.5e-4ctherm.ctherm2 6 5 = 2.5e-3ctherm.ctherm3 5 4 = 1.9e-3ctherm.ctherm4 4 3 = 2.6e-3ctherm.ctherm5 3 2 = 5.5e-3ctherm.ctherm6 2 tl = 1.8e-2 rtherm.rtherm1 th 6 = 3.1e-2

rtherm.rtherm2 6 5 = 15.1e-2 rtherm.rtherm3 5 4 = 4.2e-1 rtherm.rtherm4 4 3 = 8.4e-1 rtherm.rtherm5 3 2 = 8.7e-1 rtherm.rtherm6 2 tl = 1.5 }





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